## NSN 5962-01-160-3258

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inch	es and 0.310 inches
Body Height:	
).185 inches	
Maximum Power D	issipation Rating:
739.0 milliwatts	
Operating Tempura	ature Range:
55.0/+125.0 degree	s celsius
Storage Tempurati	ire Range:
65.0/+150.0 degree	s celsius
End Application:	
An/fps-117 radar sy	stem
eatures Provided	
Bipolar and monolith	ic and schottky and programmable and w/active pull-up
nclosure Material:	
Ceramic	
nclosure Configur	ation:
Dual-in-line	
Output Logic Form	:
Fransistor-transistor	logic
nput Circuit Patter	n:
0 input	
Case Outline Sour	e And Designator:
D-2 mil-m-38510	
Ferminal Surface T	reatment:
Solder	
oltage Rating And	I Type Per Characteristic:
5.5 volts power sou	rce
Time Rating Per Cl	nacteristic:
75.00 nanoseconds	propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	be:
Rom	
Memory Capacity:	
Unknown	
Terminal Type And	Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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## Demilitarization:

Yes - demil/mli

Fiig:

A458a0

